## Electronic and optical properties of Mn–S co-doped anatase TiO<sub>2</sub> from first-principles calculations

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The electronic and optical properties of Mn-S co-doped anatase  $TiO_2$  were calculated using the plane-wave-based ultrasoft pseudopotential density functional method within its generalized gradient approximation (GGA). The calculated results show that the band gap of Mn-S co-doped  $TiO_2$  is larger than that of the pure  $TiO_2$ , and two impurity bands appear in the forbidden band, one of which above the valence band plays a vital role for the improvement of the visible light catalytic activity. The Mn-S co-doped anatase  $TiO_2$  could be a potential candidate for a photocatalyst because of its enhanced absorption ability of visible light.

Keywords: Mn-S co-doped TiO<sub>2</sub>; electronic structure; optical properties

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### 1. Introduction

Anatase titanium dioxide  $(TiO_2)$ , which is wellknown as a cheap, nontoxic, stable semiconductor material, has attracted much attention in recent decades as an interesting material for solar cells applications and the most promising photocatalyst [1-3]. However, the pure anatase TiO<sub>2</sub> has low energy conversion efficiency and, because of its fundamental band gap of 3.23 eV, absorbs only a small portion of the solar energy in the ultraviolet region (UV) which corresponds to 3 to 5 % of the sunlight. Recently, many attempts, such as surface sensitization [4], composite semiconductor coupling [5], and ion doping [6-10], have been carried out to modify the band structure of TiO<sub>2</sub>. Among these methods, doping is regarded as a promising way to modify the band edges of  $TiO_2$ and extend its photocatalytic activity to the visible spectrum, and various kinds of dopants, such as N, C, S, Cu, W, Mn [11-16], have been used to achieve the goal. Mono-doped TiO<sub>2</sub> can respond to the visible light and broaden the optical absorption

region; however, the introduction of impurity bands can easily create recombination centers for electrons and holes, which is not beneficial for activity improvement of the photocatalysts. Recent studies have shown that anion-cation co-doping can significantly improve the photocatalytic activity of  $TiO_2$ , as the co-doping ions can reduce the recombination centers and effectively improve the charge carriers migration efficiency, therefore, enhance the photocatalytic activity of  $TiO_2$  [17].

Many studies have been performed to investigate the effects of Mn and S mono-doping on the optical absorption of TiO<sub>2</sub>. Umebayashi et al. [13, 18] successfully synthesized S-doped TiO<sub>2</sub> (S/TiO<sub>2</sub>) by oxidation annealing of TiS<sub>2</sub>. They found that the S atoms replaced O atoms and the S/TiO<sub>2</sub> showed optical redshift. Cui et al. [19] calculated the electronic structures and optical absorption spectra of S/TiO<sub>2</sub> by means of first-principles calculations. The results indicated that the isolated S 3p states that appeared at the upper edge of the valence band caused the narrowing of the band gap of S/TiO<sub>2</sub>; Zhang et al. [20] prepared Mndoped TiO<sub>2</sub> (Mn/TiO<sub>2</sub>) films by sol-gel method. They found that the sample with the dopant

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concentration of 0.7 at.% had the highest activity based on the degradation rate of methyl orange. Binas et al. [21] synthesized Mn/TiO<sub>2</sub> nanostructured powders by sol-gel method, and they found that the photocatalytic activity of 0.1 % Mn:TiO<sub>2</sub> was higher than that of the other photocatalytic materials with different concentrations (0.5 % and 1 %) under both UV and visible light.

As far as we know, neither experimental nor theoretical studies have been reported on the Mn–S co-doped anatase  $TiO_2$  (Mn–S/TiO<sub>2</sub>). Therefore, in this paper, the plane-wave-based ultrasoft pseudopotential method, based on the density functional theory within the GGA, has been utilized to obtain a fundamental insight into the effects of Mn–S co-doping of the anatase  $TiO_2$ , aiming at prediction of the interplay of the co-dopants on the energy band structure of anatase  $TiO_2$  and providing a theoretical basis for the experimental study.

### 2. Calculation model and method

Anatase TiO<sub>2</sub> has a tetragonal structure (space group: I4<sub>1</sub>/amd, local symmetry:  $D_{4h}^{19}$ ), and contains four Ti atoms and eight O atoms in the primitive cell. The doping system was constructed from a relaxed (3 × 3 × 1) 108-atom anatase supercell. The large supercell was used to minimize possible artificial Coulomb interactions between impurity ions in neighboring supercells. In order to reduce the influence of boundary effects, the central Ti atom was replaced by Mn and the neighboring O by S. The doping model is shown in Fig. 1, with the corresponding doping concentrations of 0.93 at.% for mono-doping and 1.85 at.% for co-doping.

The non-spin-polarized density functional theory (DFT) calculations were performed by the CASTEP [22] program on the basis of the plane-wave method within a generalized gradient approximation, with the exchange-correlation function of Perdew-Burke-Ernzerhof (PBE). The interactions between valence electrons and the ionic core were described by ultrasoft pseudopotential, which was used with Ti:  $3s^23p^63d^24s^2$ , O:  $2s^22p^4$ , Mn:  $3d^54s^2$  and S:  $3s^23p^4$  as

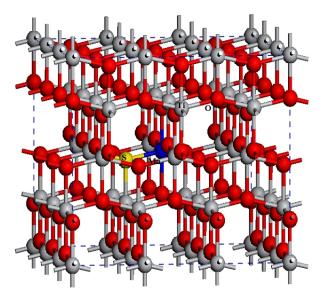


Fig. 1. Structural model of the Mn–S/TiO<sub>2</sub>.

the valence electrons configuration. We chose the cut-off energy of 300 eV for all the computations. The special points sampling integration over the Brillouin zone was carried out using the Monkhorst-Pack method with a  $2 \times 2 \times 2$  special-point mesh. All of the structures were allowed to relax using the Broyden-Fletcher-Goldfarb-Shanno (BFGS) quasi-Newton scheme with the convergence threshold for the maximum energy change of  $2.0 \times 10^{-5}$  eV/atom, and the maximum force, maximum stress and maximum displacement tolerances set as 0.05 eV/Å, 0.1 GPa, and 0.002 Å, respectively. These parameters are sufficient for well-converged total energy and structural transition calculations.

### 3. Results and discussion

# **3.1.** Structural properties and formation energies

After geometry optimization, the lattice parameters were a = b = 3.8078 Å and c = 9.8213 Å, which was in good consistency with experimental [23] and theoretical [24] data.

To examine the relative difficulties of incorporating different ions into the lattice, the dopant formation energies were calculated according to the formula below:

$$E(S/TiO_2)_{form} = E(doped) - E(pure) - \mu_S + \mu_O$$
(1)

$$E(Mn/TiO_2)_{form} = E(doped) - E(pure) - \mu_{Mn} + \mu_{Ti}$$
(2)

$$E(Mn - S/TiO_2)_{form} = E(doped) - E(pure)$$
$$-\mu_{Mn} - \mu_S + \mu_O + \mu_{Ti}$$
(3)

where E(doped) is the total energy of TiO<sub>2</sub> with dopant, and E(pure) is the total energy of the supercell of pure TiO<sub>2</sub>,  $\mu_S$  is the chemical potential of S, which is determined by the energy of SO<sub>2</sub> molecule ( $\mu_S = \mu_{SO_2} - \mu_{O_2}$ ),  $\mu_{Mn}$  represents the calculated chemical potential of Mn from bulk atoms. The growth of an engineered TiO<sub>2</sub> is not an equilibrium process but a variable determined by a growing environment [25], which can be either Ti-rich, O-rich, or anything in-between. Under Ti-rich conditions, the  $\mu_{Ti}$  chemical potential is assumed to be the energy of bulk Ti, while the  $\mu_O$  chemical potential is determined by the following formula:

$$2\mu_O + \mu_{Ti} = \mu_{TiO_2} \tag{4}$$

Under O-rich conditions, the  $\mu_O$  chemical potential is calculated from the ground-state energy of the  $O_2$ molecule ( $\mu_O = 1/2\mu_{O_2}$ ), while  $\mu_{Ti}$  is obtained by formula 4. The calculated formation energies are listed in Table 1.

Table 1. Formation energies (eV)  $E_{form}$  for Mn, S, and Mn–S co-doped TiO<sub>2</sub>.

E <sub>form</sub>	Ti-rich	O-rich	
Mn-doped	7.00083	-3.60248	
S-doped	3.96403	9.26558	
Mn-S codoped	9.99344	4.69175	

From Table 1 it can be seen that under Ti-rich condition, the formation energies of the three kinds of doping are positive, which indicates that if these three kinds of doping were carried out in the experiment, it would be a thermonegative reaction. On the other hand, under O-rich condition, the results indicate that the experiments of S-doping and Mn–S co-doping should be thermonegative reactions, but Mn-doping experiment should be an exothermic reaction. By comparison of the data on formation energies, we concluded that the Mn/TiO<sub>2</sub> and Mn–S/TiO<sub>2</sub> are easy to form in oxygen enrichment condition. However, the S/TiO<sub>2</sub> is easy to form in titanium enrichment condition.

# **3.2.** Population analysis and electron density

The charge density on the  $(0\ 0\ 1)$  surfaces of TiO<sub>2</sub>, Mn/TiO<sub>2</sub>, S/TiO<sub>2</sub> and Mn–S/TiO<sub>2</sub> were plotted to study the origin of the band gap modifications, the charge distribution and transfer caused by Mn–S co-doping, as shown in Fig. 2. The atomic populations of dopants in the doping systems are listed in Table 2.

Table 2. Atomic populations of doped TiO<sub>2</sub> supercell.

Species	S	р	d	Total	charge [e]
Mn/TiO <sub>2</sub> :Mn	0.30	0.32	5.44	6.06	0.94
S/TiO <sub>2</sub> :S	1.80	4.54	0.00	6.34	-0.34
Mn-S/TiO2:Mn	0.29	0.36	5.59	6.24	0.76
Mn-S/TiO2:S	1.82	4.35	0.00	6.17	-0.17

From Table 2 we can know that the charge of  $Mn \text{ in } Mn-S/TiO_2$  is less than in  $Mn/TiO_2$ , and the charge of S in  $Mn-S/TiO_2$  is larger than in  $S/TiO_2$ . These results mean that the strength of the covalent bond between Mn and S in  $Mn-S/TiO_2$  is weaker than the Mn–O bond in  $Mn/TiO_2$  and the Ti–S bond in  $S/TiO_2$ .

As it can be seen in Fig. 2b, the strength of the covalent bond of Mn–O is weaker than that of Ti–O, and this is probably due to the weaker electropositivity of Mn than that of Ti. In Fig. 2c, it is very clear that the strength of the covalent bond of Ti–S is weaker than that of Ti–O, and this is because of the lower electronegativity of S than that of O. Due to the weaker electropositivity of Mn and electronegativity of S, the strength of covalent bonds of Mn–S and Ti–S is weaker than those of Mn–O and Ti–O.

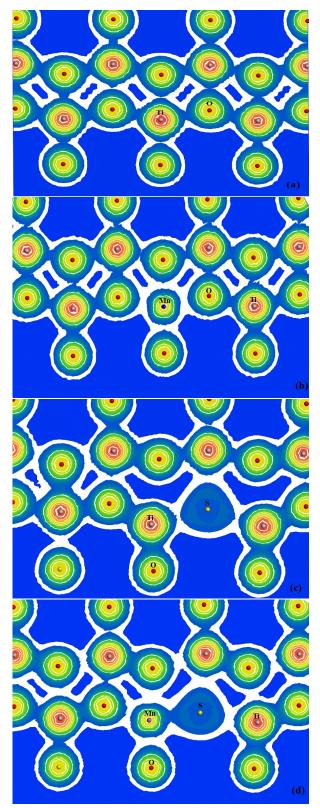
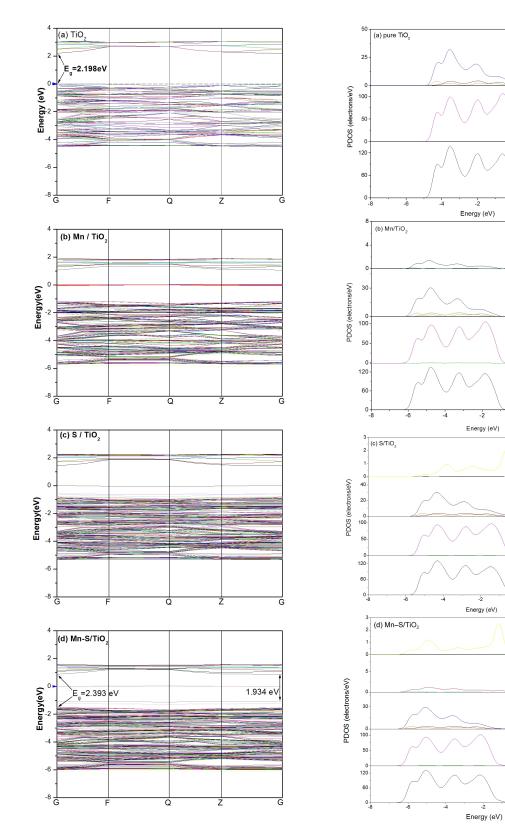


Fig. 2. Two-dimensional profiles of (a) pure  $TiO_2$ , (b)  $Mn/TiO_2$ , (c)  $S/TiO_2$ , (d)  $Mn-S/TiO_2$ .

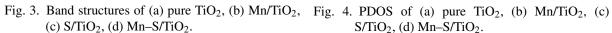
#### **3.3.** Band structures and density of states

To compare the doping effects of different doping elements on the energy band of TiO<sub>2</sub>, the band structures of pure TiO2, Mn/TiO2, S/TiO2, and Mn-S/TiO<sub>2</sub> along the high symmetry points across the first Brillouin zone were illustrated in Fig. 3. Because a lot of theoretical calculations of Mn/TiO<sub>2</sub> [26–28] and S/TiO<sub>2</sub> [19, 29, 30] have been reported, we will not concentrate on the detailed research on them. But for contrast, we also calculated the energy band of Mn/TiO<sub>2</sub> and S/TiO<sub>2</sub>. The Fermi level was set as the highest filled level of the electrons. The corresponding total and partial densities of states (DOS and PDOS) are shown in Fig. 4. They have been used to further analysis of the constitution of valence band (VB) and conduction band (CB), and to understand the changes of electronic structures caused by Mn-S co-doping. The VB, which is located between -4.506 eV and the Fermi level, was formed by the bonding states of the hybridized O 2p-Ti 3d orbitals with a minor contribution from Ti 3p and Ti 4s oribitals. The CB located between 2.198 and 3.074 eV above the Fermi level was formed primarily by the Ti 3d orbitals with a minor contribution from O 2p orbitals. Obviously, the calculated band gap of TiO<sub>2</sub> is 2.198 eV [31] as shown in Fig. 3a, which is largely underestimated compared with the experimental [32] band gap of 3.2 eV due to the inherent drawback of the ideal electron gas model in GGA approach. It is because of the DFT limitations, as the discontinuity in the exchange correlation potential has not been taken into account [33-35]. However, these results are reliable and advisable for the qualitative analysis and do not affect the accuracy of comparing the related properties of crystals.

From Fig. 3d and Fig. 4d it can be seen that the VB of  $Mn-S/TiO_2$  has been formed by the bonding states of the hybridized O 2p-Ti 3d-S 3p orbitals with minor contributions from Mn 3d, Ti 3p and Ti 4s orbitals. The CB of  $Mn-S/TiO_2$  above the Fermi level is formed primarily by the Ti 3d and Mn 3d orbitals with minor contributions from O 2p and S 3p oribitals. This indicates that the electrons and holes can be separated effectively and then improve the photocatalytic efficiency of TiO<sub>2</sub> due to



(c) S/TiO<sub>2</sub>, (d) Mn–S/TiO<sub>2</sub>.



Ti 4s Ti 3p Ti 3d

- O 2s - O 2p

total

Mn 4s Mn 3d

- Ti 4s - Ti 3p - Ti 3d

- O 2s - O 2p

- total

- S 3s - S 3p

Mn 4s Mn 3d

-Ti4s -Ti3p -Ti3d

- O 2s - O 2p

—— total

- S 3s - S 3p

Ti 4s Ti 3p Ti 3d

– O 2s – O 2p

- Total

bottom of the CB. The calculated band gap of the Mn–S/TiO<sub>2</sub> is 2.393 eV, which is 0.195 eV larger than that of the intrinsic  $TiO_2$ . It was found that there are two impurity bands in the band gap: one is located near the Fermi level including three impurity energy levels, and another is located above the VB which contains two energy levels. The impurity band located between the VB and the Fermi level is mainly composed of S 3p orbital, which is filled up by electrons, and the electrons in this impurity band can be excited to the CB. From the calculation results, it was found that the distance between this impurity band and the CB is 1.934 eV, which is less than the band gap of  $TiO_2$ , equal to 2.198 eV. This would be very advantageous to the electronic transition and has an important influence on the absorption of light, which is confirmed by the optical absorption spectra in Fig. 5. The impurity band is located near the Fermi level including three energy levels composed of mainly hybridized Mn 3d-S 3p orbitals. This impurity band can act as the bridge for the electron transition and enhance the light absorption. However, it can also act as recombination centers [36].

the energy levels crossed with each other at the

#### **Optical properties** 3.4.

In order to explore the absorption properties, the optical absorption spectra of pure anatase TiO<sub>2</sub>, Mn/TiO<sub>2</sub>, S/TiO<sub>2</sub> and Mn–S/TiO<sub>2</sub> were calculated on the basis of the detailed electronic band structure as shown in Fig. 5. Because of the underestimated band gap of pure TiO<sub>2</sub>, we induced a scissors operator of 1.032 eV (band gap difference between experimental and calculated value) for obtaining an exact optical absorption spectra in the visible region. It is obvious that the absorption edges of Mn/TiO<sub>2</sub>, S/TiO<sub>2</sub> and Mn-S/TiO<sub>2</sub> move toward the longer wavelength, which means enhancement of visible light absorption. Mn-S/TiO<sub>2</sub> has stronger light absorption in the visible region compared with pure TiO<sub>2</sub>, Mn/TiO<sub>2</sub>, and S/TiO<sub>2</sub>. This implies that the Mn–S/TiO<sub>2</sub> probably has a higher photocatalytic activity. Actually, there are many factors affecting the photocatalytic efficiency of TiO<sub>2</sub>, in addition to external conditions (such as light source, time, temperature, and the pH value of reaction system), and also including intrinsic characteristics of TiO<sub>2</sub>, especially specific surface area, impurity energy levels or bands, and defects. In this paper, we mainly consider the effects of impurity bands and we think the impurity bands play an important role, especially the one between the Fermi level and the VB. Because this impurity band can act as a "step" which reduces the electronic transition energy, it means that more electrons can be excited. More excited electrons means greater probability that photo-excited electrons can migrate to the surface. Meanwhile, the impurity energy levels or band could also act as a separating center. The photo-excited electrons-holes can separate rapidly and effectively, which will promote the carriers diffusion and enhance the charge carrier lifetime. Therefore, the quantum transformation efficiency can be improved, which will lead to the enhancement of the photocatalytic efficiency of Mn-S/TiO<sub>2</sub>.

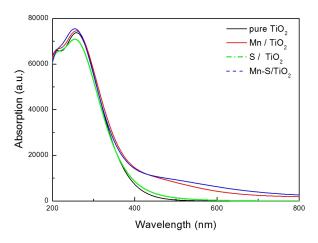


Fig. 5. Absorption spectra of pure TiO<sub>2</sub>, Mn/TiO<sub>2</sub>, S/TiO<sub>2</sub> and Mn–S/TiO<sub>2</sub>.

#### 4. Conclusions

First-principles method has been employed to study the effects of Mn-S co-doping on the electronic and optical properties of anatase TiO<sub>2</sub>. The calculation on Mn-S/TiO2 with GGA shows that the introduction of Mn and S induces two impurity bands in the forbidden band. The impurity band, especially the one located between the Fermi level and the VB causes the obvious redshift and absorption enhancement in the visible region for  $Mn-S/TiO_2$ . Therefore, Mn-S co-doping is a fine choice for enhancing the photocatalytic activity of TiO<sub>2</sub>.

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#### References

- WEI B.L., CHEN Y.P., YE M.J., SHAO Z.H., HE Y., SHI Y., *Plasma Chem. Plasma P.*, 35 (2015), 173.
- [2] ANGTHARARUK D., SUTTHIVAIYAKIT P., BLAISE C., GAGNÉ F., SUTTHIVAIYAKIT S., *Environ. Sci. Pollut. R.*, 22 (2015), 1468.
- [3] PAPOULIS D., KORDOULI E., LAMPROPOULOU P., RAPSOMANIKIS A., KORDULIS C., PANAGIO-TARAS D., THEOPHYLAKTOU K., STATHATOS E., KOMARNENI S., J. Surf. Interfac. Mater., 2 (2014), 261.
- [4] ZHAN L.L., CHEN H.F., YE J.Q., Adv. Mater. Res., 531 (2012), 387.
- [5] HUANG J.M., LIU Y.Y., LU L.F., LU L., Res. Chem. Intermediat., 38 (2012), 487.
- [6] VARLEY J.B., JANOTTI A., WALLE C.G.V.D., Adv. Mater., 23 (2011), 2343.
- [7] ZUO F., BOZHILOV K., DILLON R. J., WANG L., SMITH P., ZHAO X., BARDEEN C., FENG P.Y., Angew. Chem. Int. Edit., 124 (2012), 6327.
- [8] YAMADA N., HITOSUGI T., KASAI J., HIROSE Y., SHIMADA T., HASEGAWA T., J. Appl. Phys., 105 (2009), 123702.
- [9] PAL U., GHOSH S., CHATTERJEE D., Transit. Metal. Chem., 37 (2012), 93.
- [10] YANG X. X., CAO C. D., HOHN K., ERICK-SON L., MAGHIRANG R., HAMAL D., KLABUNDE K., *J. Catal.*, 252 (2007), 296.
- [11] CEOTTO M., PRESTI L.L., CAPPELLETTI G., MERONI D., SPADAVECCHIA F., ZECCA R., LEONI M., SCARDI P., BIANCHI C.L., ARDIZ-ZONE S., J. Phys. Chem. C, 116 (2012), 1764.
- [12] YANG K., DAI Y., HUANG B.B., WHANGBO M.H., J. Phys. Chem. C, 113 (2009), 2624.
- [13] UMEBAYASHI T., YAMAKI T., ITOH H., ASAI K., *Appl. Phys. Lett.*, 81 (2002), 454.

- [14] WU B., ZHUANG W.Q., SAHU M., BISWAS P., TANG Y.J., Sci. Total Environ., 409 (2011), 4635.
- [15] CHEN D.M., XU G., MIAO L., CHEN L.H., NAKAO S., JIN P., J. Appl. Phys., 107 (2010), 063707.
- [16] FENG H.J., ZHANG M. H., YU L.E., Appl. Catal. A-Gen., 413 – 414 (2012), 238.
- [17] LI M., ZHANG J.Y., ZHANG Y., Chem. Phys. Lett., 527 (2012), 63.
- [18] UMEBAYASHI T., YAMAKI T., TANAKA S., ASAI K., *Chem. Lett.*, 32 (1) (2003), 330.
- [19] CUI Y., DU H., WEN L.S., Solid State Commun., 149 (2009), 634.
- [20] ZHANG K.J., XU W., LI X.J., ZHENG S.J., XU G., Cent. Eur. J Chem., 4 (2006), 234.
- [21] BINAS V.D., SAMBANI K., MAGGOS T., KAT-SANAKI A., KIRIAKIDIS G., *Appl. Catal. B-Environ.*, 113 – 114 (2012), 79.
- [22] CLARK S.J., SEGALL M.D., PICKARD C.J., HASNIP P.J., PROBERT M.I., REFSON K., PAYNE M.C., Z. Kristallogr., 220 (2005), 567.
- [23] BURDETT J.K., HUGHBANDK T., MILLER G.J., RICHARDSON JR J.W., SMITH J.V., J. Am. Chem. Soc., 109 (1987), 3639.
- [24] LIU X.S., JIANG E.Y., LI Z.Q., SONG Q.G., *Appl. Phys. Lett.*, 92 (2008), 252104.
- [25] VALENTIN C.D., PACCHIONI G., SELLONI A., Chem. Mater., 17 (2005), 6656.
- [26] UMEBAYASHI T., YAMAKI T., ITOH H., ASAI K., J. Phys. Chem. Solids, 63 (2002), 1909.
- [27] ZHANG X.J., LIU Q.J., DENG S.G., CHEN J., GAO P., Acta Phys. Sin.-Ch. Ed., 60 (2011), 087103.
- [28] ZHONG X.C., PAN Z.G., WEI Z.G., XU G., XU Y.Y., Comput. Appl. Chem., 28 (2011), 685.
- [29] MATSUSHIMA S., TAKEHARA K., YAMANE H., YA-MADA K., NAKAMURA H., ARAI M., KOBAYASHI K., J. Phys. Chem. Solids, 68 (2007), 206
- [30] WU G.H., ZHENG S.K., JIA C.J., LIU L., Acta Phys. Sin.-Ch. Ed., 61 (2012), 223101.
- [31] ZHENG S. K., WU G. H., LIU L., *Acta Phys. Sin.-Ch. Ed.*, 62 (2013), 043102.
- [32] TANG H., BERGER H., SCHMID P.E., LÉVY F., BURRI G., Solid State Commun., 23 (1977), 161.
- [33] STAMPFL C., VAN DE WALLE C.G., *Phys. Rev. B*, 59 (1999), 5521.
- [34] PERDEW J.P., MEL L., Phys. Rev. Lett., 51 (1983), 1884.
- [35] LEE J.Y., PARK J., CHO J.H., Appl. Phys. Lett., 87 (2005), 011904.
- [36] LONG R., ENGLISH J.N., Appl. Phys. Lett., 98 (2011), 142103.

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